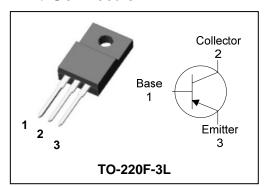


PNP Silicon Transistor

Features

- · Low saturation switching application
- Power amplifier
- High Voltage : V_{CEO}=-80V Min.
- Complement to STD1408PI

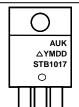
PIN Connection



Ordering Information

Type NO.	Marking	Package Code		
STB1017PI	STB1017	TO-220F-3L		

Marking Diagram



Column 1: Manufacturer

Column 2 : Production Information $-\Delta$: Factory Management Code

- YMDD: Date Code (Year, Month, Date)

Column 3: Device Code

Absolute maximum ratings

Characteristic	Symbol	Rating	Unit
Collector-Base voltage	V_{CBO}	-80	V
Collector-Emitter voltage	V_{CEO}	-80	V
Emitter-base voltage	V_{EBO}	-5	V
Collector ourrent	I _C	-4	А
Collector current	I _{CP} *	-8	A(Pulse)
Collector Power dissipation (Tc=25℃)	P _C	15	W
Junction temperature	T _j	150	°C
Storage temperature	T_{stg}	-55~150	°C

^{*:} Single pulse, tp= 300 μ s

Char	acteristic	Symbol	Typ.	Max	Unit
Thermal	Junction-case	$R_{th(J-C)}$	1	8.33	°C/W
resistance	Junction-ambient	R _{th(J-a)}	1	62.5	C/VV

KSD-T0O110-000

Electrical Characteristics

Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Collector cut-off current	I _{CBO}	V _{CB} =-80V, I _E =0	-	-	-10	μА
Emitter cut-off current	I _{EBO}	$V_{EB}=-5V$, $I_{C}=0$	-	-	-10	μА
Collector-Emitter breakdown voltage	V _{(BR)CEO}	I _C =-50mA, I _B =0	-80	-	-	V
DC current gain	h _{FE}	$V_{CE} = -5V, I_{C} = -0.5A$	120	-	240	-
		V_{CE} =-5V, I_{C} =-3A	40	-	-	-
Collector-Emitter saturation voltage	V _{CE(sat)}	$I_{C}=-3A$, $I_{B}=-0.3A$	-	-1.0	-1.7	V
Base-Emitter saturation voltage	V _{BE(on)}	V_{CE} =-5V, I_B =-3A	-	-1.0	-1.5	V
Transition frequency	f _T	V _{CB} =-5V, I _C =-0.5A	-	9	-	MHz
Collector output capacitance	C_ob	V _{CB} =-10V, I _E =0, f=1MHz	-	60	-	pF

^{*} hFE rank : 120~240 Only

KSD-T0O110-000 2

Electrical Characteristic Curves

Fig. 1 P_C - T_a

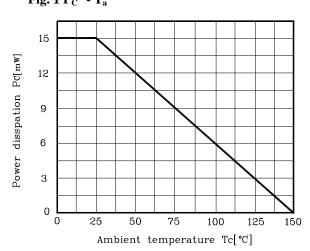


Fig. 2 I_C - V_{BE}

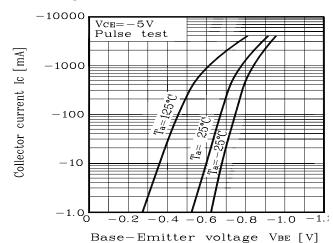


Fig. 3 $I_{\rm C}~$ - $V_{\rm CE}$

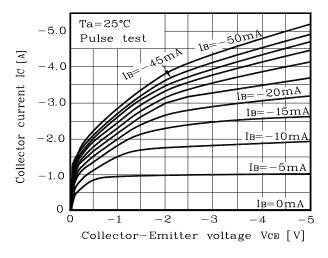


Fig. 4 h_{FE} - I_{C}

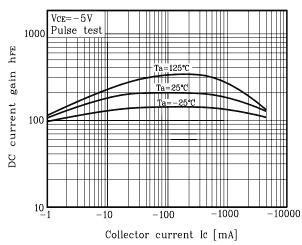


Fig. 5 $V_{\text{CE(sat)}}$ - I_{C}

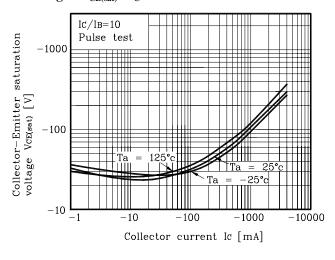
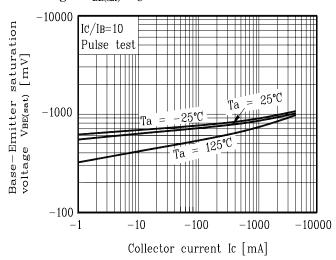


Fig. 6 $V_{BE(sat)}$ - I_C



KSD-T0O110-000 3

Electrical Characteristic Curves

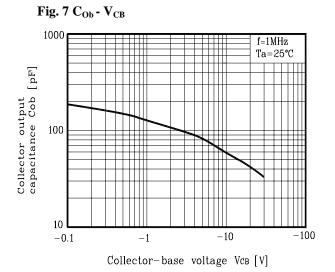
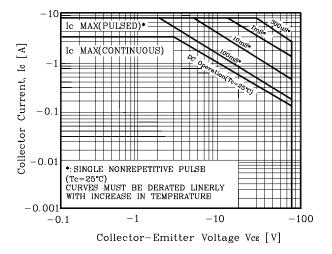


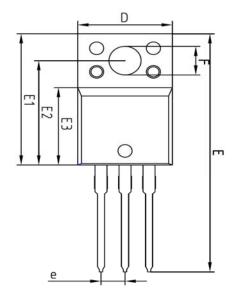
Fig. 8 Safe Operating Area

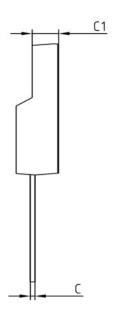


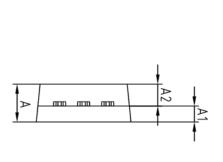
KSD-T0O110-000

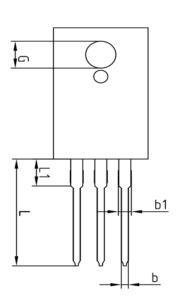
4

Outline Dimension









	MILLIMETERS			NOTE	
SYMBOL	MINIMUM	NOMINAL	MAXIMUM	NOIE	
Α	-	_	4.60		
A1	2.45	2.50	2.55		
A2	1.95	2.00	2.05		
Ь	0.65	0.75	0.85		
b1	1.07	1.27	1.47		
С	0.40	0.50	0.60		
C1	2.70	2.80	2.90		
D	9.90	10.00	10.10		
Ε	28.00	_	28.60		
E1	15.50	15.60	15.70		
E2	12.30	12.40	12.50		
E3	9.15	9.20	9.25		
F	3.30	3.40	3.50		
G	3.10	3.20	3.30		
е	2.54 BSC				
L	12.40	_	13.00		
L1	3.46 BSC				

KSD-T0O110-000 5

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KSD-T00110-000 6